

isc Silicon PNP Power Transistor

BD136

DESCRIPTION

- DC Current Gain-
 - : h_{FE}= 40(Min)@ I_C= -0.15A
- · Collector-Emitter Sustaining Voltage -
 - : V_{CEO(SUS)}= -45V(Min)
- Complement to type BD135
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



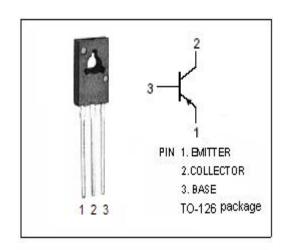
 Designed for use as audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

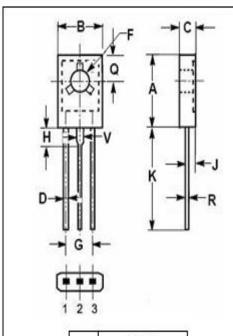


ABSOLUTE MAXIMUM RATINGS(Ta-25 C)				
SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-45	V	
VCEO	Collector-Emitter Voltage	-45	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ic	Collector Current-Continuous	-1.5	А	
I _B	Base Current-Continuous	-0.5	А	
Pc	Collector Power Dissipation @ T _a =25°C	1.25	\A/	
	Collector Power Dissipation @ T _C =25 °C	12.5	W	
TJ	Junction Temperature	150	$^{\circ}$ C	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	10	°C/W
R _{th j-a}	Thermal Resistance,Junction to Ambient	100	°C/W





	mm	
DIM	MIN	MAX
Α	10.70	10.95
В	7.70	7.90
С	2.60	2.80
D	0.66	0.86
F	3.10	3.30
G	4.48	4.68
Н	2.00	2.20
J	1.35	1.55
K	15.30	16.30
Q	3.70	3.90
R	0.40	0.60
٧	1.17	1.37



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -30mA ; I _B =0	-45			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -0.5A; I _B = -50mA			-0.5	V		
V _{BE(on)}	Base-Emitter On Voltage	I _C = -0.5A; V _{CE} = -2V			-1.0	V		
I _{CBO}	Collector Cutoff Current	V _{CB} = -30V; I _E = 0 V _{CB} = -30V; I _E = 0,T _C =125°C			-0.1 -10	μА		
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-10	μА		
h _{FE-1}	DC Current Gain	I _C = -5mA ; V _{CE} = -2V	25					
h _{FE-2}	DC Current Gain	I _C = -0.5A ; V _{CE} = -2V	25					
h _{FE-3}	DC Current Gain	Ic= -0.15A ; V _{CE} = -2V	40		250			



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